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Inclosure Material: Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Function For Which Designed:** Current regulator **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 Electrode Internally-electrically Connected To Case: Gate **Mounting Method:** Terminal **Features Provided:** Insulator **Semiconductor Material:** Silicon

Voltage Rating In Volts Per Characteristic:

40.0 drain to gate voltage and 3.0 drain to source voltage

Current Rating Per Characteristic:

100.00 milliamperes zero-gate-voltage drain current

Power Rating Per Characteristic:

1.8 watts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Mtd to beryllia insulator - handle insulator as hazardous material

Test Data Document:

16340-80001-33 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

16340-261223 manufacturers specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

